NSN 5961-01-463-4333

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-463-4333 **Inclosure Material:** Glass **Overall Length:** 2.900 millimeters **Overall Height:** 1.400 millimeters **Overall Width:** 2.800 millimeters **End Application:** 6625-01-425-2551 **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 6.3 on-state voltage, dc **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current pascal **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 150.0 degrees celsius case **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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